

The clean copy of the paragraph is:

The invention is in the field of the plastic circuitry and components being employed in electronic technology, and in particular to devices containing N,N" 3,4,9,10 perylene tetracarboxylic acid diimide semiconductor materials in such devices as organic thin film transistors.

Page 3 in the paragraph beginning on line 6

In line 6 change "The each" to -Each- and in line 8 change " N,N" 3,4,9,10 perylene tetracarboxylic acid diimide" to- N,N"-di(n-1H,1H-perfluooctyl)perylene 3,4,9,10- tetracarboxylic acid diimide- by erasing the cross hatched ~~//The//each//~~ and replacing with the underlined Each , and erasing the cross hatched ~~/// of the invention /// N,N" 3,4,9,10 perylene tetracarboxylic acid diimide ///~~ and inserting the underlined N,N"-di(n-1H, 1H-perfluorooctyl) perylene 3,4,9,10- tetracarboxylic acid diimide.

The clean copy is:

An organic TFT is shown in Figs 1 & 2. Each TFT contains a source electrode 10, a drain